



#### 20V P-Channel Enhancement Mode MOSFET

Voltage -20 V Current -3.1A

#### **Features**

- RDS(ON), VGS@-4.5V, ID@-3.1A<100mΩ
- RDS(ON) , VGS@-2.5V, ID@-2.0A<135mΩ</li>
- RDS(ON) , VGS@-1.8V, ID@-1.1A<190mΩ</li>
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

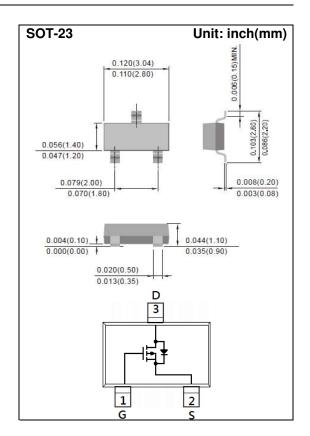
#### **Mechanical Data**

Case: SOT-23 Package

Terminals : Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.0003 ounces, 0.0084 grams

Marking: A11



### **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	-20	V
Gate-Source Voltage		$V_{GS}$	<u>+</u> 12	V
Continuous Drain Current		I <sub>D</sub>	-3.1	Α
Pulsed Drain Current		I <sub>DM</sub>	-12.4	Α
Power Dissipation	T <sub>a</sub> =25°C	$P_{D}$	1.25	W
	Derate above 25°C		10	mW/°C
Operating Junction and Storage Temperature Range		$T_{J}, T_{STG}$	-55~150	°C
Typical Thermal resistance				
- Junction to Ambient (Note 3)		$R_{\theta JA}$	100	°C/W





# **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	$BV_{DSS}$	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=-250uA$	-0.4	-0.71	-1.2	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-3.1A	-	84	100	mΩ
		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-2.0A	-	104	135	
		V <sub>GS</sub> =-1.8V, I <sub>D</sub> =-1.1A	-	134	190	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-20V, V <sub>GS</sub> =0V	-	-0.01	-1	uA
Gate-Source Leakage Current	$I_{GSS}$	V <sub>GS</sub> = <u>+</u> 12V, V <sub>DS</sub> =0V	-	<u>+</u> 10	<u>+</u> 100	nA
Dynamic						
Total Gate Charge	$Q_g$	V <sub>DS</sub> =-10V, I <sub>D</sub> =-3.1A, V <sub>GS</sub> =-4.5V <sup>(Note 1,2)</sup>	-	5.4	-	nC
Gate-Source Charge	$Q_gs$		-	0.7	-	
Gate-Drain Charge	$Q_gd$		-	1.3	-	
Input Capacitance	Ciss	V <sub>DS</sub> =-10V, V <sub>GS</sub> =0V, f=1.0MHZ	-	416	-	pF
Output Capacitance	Coss		-	43	-	
Reverse Transfer Capacitance	Crss	1-1.0WI12	-	32	-	
Switching						
Turn-On Delay Time	td <sub>(on)</sub>	\/ - 10\/   - 2.1\	-	4	-	ns
Turn-On Rise Time	tr	$V_{DD}$ =-10V, $I_{D}$ =-3.1A, $V_{GS}$ =-4.5V, $R_{G}$ =6Ω (Note 1,2)	-	27	-	
Turn-Off Delay Time	td <sub>(off)</sub>		-	78	-	
Turn-Off Fall Time	tf	N <sub>G</sub> -012	-	45	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	Is		_	_	-1.5	Α
Diode Forward Current	'S		_		-1.5	
Diode Forward Voltage	$V_{\text{SD}}$	I <sub>S</sub> =-1.0A, V <sub>GS</sub> =0V	-	0.8	-1.2	V

#### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited





#### **TYPICAL CHARACTERISTIC CURVES**

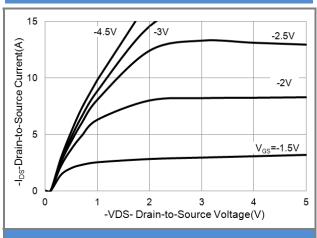
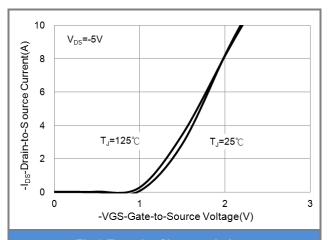


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

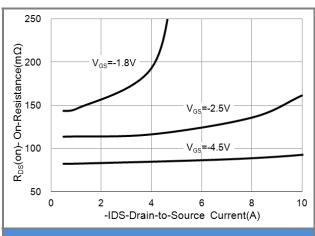


Fig.3 On-Resistance vs. Drain Current

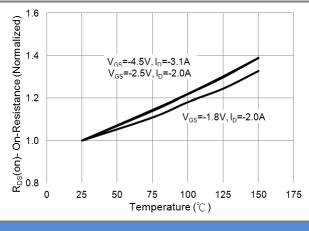
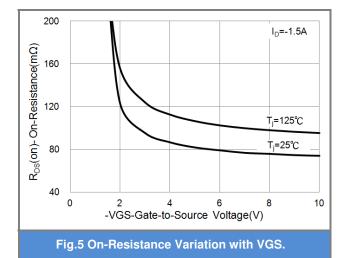
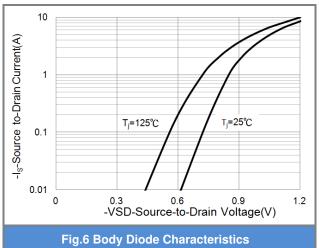


Fig.4 On-Resistance vs. Junction temperature









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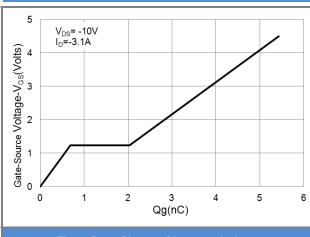
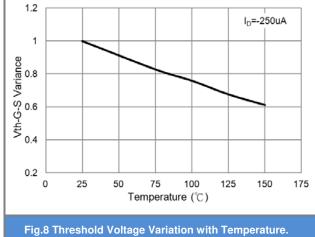


Fig.7 Gate-Charge Characteristics



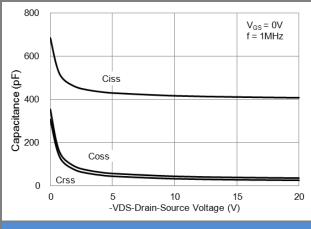


Fig.10 Capacitance vs. Drain-Source Voltage.

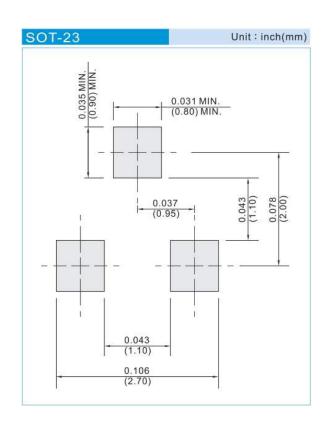




#### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJA3411_R1_00001	SOT-23	3K pcs / 7" reel	A11	Halogen free
PJA3411_R2_00001	SOT-23	12K pcs / 13" reel	A11	Halogen free

#### **MOUNTING PAD LAYOUT**







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